ESP-WROOM-32 Datasheet



Espressif Systems

December 9, 2016

About This Guide

This document provides introduction to the specifications of the ESP-WROOM-32 module. The document structure is as follows:

Chapter	Title	Subject	
Chapter 1	Preface	An overview of ESP-WROOM-32	
Chapter 2	Pin Definitions	Device pinout and pin descriptions	
Chapter 3	Functional Description	Description of major functional modules and protocols	
Chapter 4	Electrical Characteristics	Electrical characteristics and specifications of ESP-WROOM-32	
Chapter 5	Schematics	The schematics of ESP-WROOM-32	

Release Notes

Date	Version	Release notes
2016.08	V1.0	First release
2016.11	V1.1	Updated Chapter 5
2016.11	V1.2	Added Peripheral Schematics
2016.12	V1.3	Updated Chapter 2.1

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1. Preface

ESP-WROOM-32 is a powerful, generic WiFi-BT-BLE MCU module that targets a wide variety of applications, ranging from low-power sensor networks to the most demanding tasks, such as voice encoding, music streaming and MP3 decoding.

At the core of this module is the ESP32 chip, which is designed to be scalable and adaptive. There are 2 CPU cores that can be individually controlled or powered, and the clock frequency is adjustable from 80 MHz to 240 MHz. The user may also power off the CPU and make use of the low-power coprocessor to constantly monitor the peripherals for changes or crossing of thresholds. ESP32 integrates a rich set of peripherals, ranging from capacitive touch sensors, Hall sensors, low-noise sense amplifiers, SD card interface, Ethernet, high speed SDIO/SPI, UART, I2S and I2C.

The integration of Bluetooth, Bluetooth LE and Wi-Fi ensures that a wide range of applications can be targeted, and that the module is future proof: using Wi-Fi allows a large physical range and direct connection to the internet through a Wi-Fi router, while using Bluetooth allows the user to conveniently connect to the phone or broadcast low energy beacons for its detection. The sleep current of the ESP32 chip is less than 5 μ A, making it suitable for battery powered and wearable electronics applications. ESP-WROOM-32 supports data rates of up to 150 Mbps, and 22 dBm output power at the PA to ensure the widest physical range. As such the chip does offer industry-leading specifications and the best performance for electronic integration, range, power consumption, and connectivity.

The operating system chosen for ESP32 is freeRTOS with LWIP; TLS 1.2 with hardware acceleration is built in as well. Secure (encrypted) over the air (OTA) upgrade is also supported, so that developers can continually upgrade their products even after their release.

Table 1 provides the specifications of ESP-WROOM-32.

Categories	Items	Specifications	
	Standards	FCC/CE/IC/TELEC/KCC/SRRC/NCC	
		802.11 b/g/n/d/e/i/k/r (802.11n up to 150 Mbps)	
Wi-Fi	Protocols	A-MPDU and A-MSDU aggregation and 0.4 μ s	
		guard interval support	
	Frequency range	2.4 ~ 2.5 GHz	
	Protocols	Bluetooth v4.2 BR/EDR and BLE specification	
		NZIF receiver with -98 dBm sensitivity	
Bluetooth	Radio	Class-1, class-2 and class-3 transmitter	
		AFH	
	Audio	CVSD and SBC	
		SD card, UART, SPI, SDIO, I2C, LED PWM, Motor	
	Module interface	PWM, I2S, I2C, IR	
	Module interface	GPIO, capacitive touch sensor, ADC, DAC, LNA	
		pre-amplier	
	On-chip sensor	Hall sensor, temperature sensor	
Hardware	On-board clock	26 MHz crystal, 32 kHz crystal	
	Operating voltage	2.2 ~ 3.6V	
	Operating current	Average: 80 mA	
	Operating temperature range	-40°C ~ 85°C *	
	Ambient temperature range	Normal temperature	
	Package size	18 mm x 25.5 mm x 2.8 mm	
	Wi-Fi mode	Station/softAP/SoftAP+station/P2P	
	Security	WPA/WPA2/WPA2-Enterprise/WPS	
	Encryption	AES/RSA/ECC/SHA	
	Firmware upgrade	UART Download / OTA (via network) / download	
Software	Firmware upgrade	and write firmware via host	
	Software development	Supports Cloud Server Development / SDK for	
		custom firmware development	
	Network protocols	IPv4, IPv6, SSL, TCP/UDP/HTTP/FTP/MQTT	
	User configuration	AT instruction set, cloud server, Android/iOS App	

Table 1: ESP-WROOM-32 Specifications

Note:

* ESP-WROOM-32 with the industry-standard temperature range (-40°C \sim 125°C) is available for custom order.

2. Pin Definitions

2.1 Pin Layout

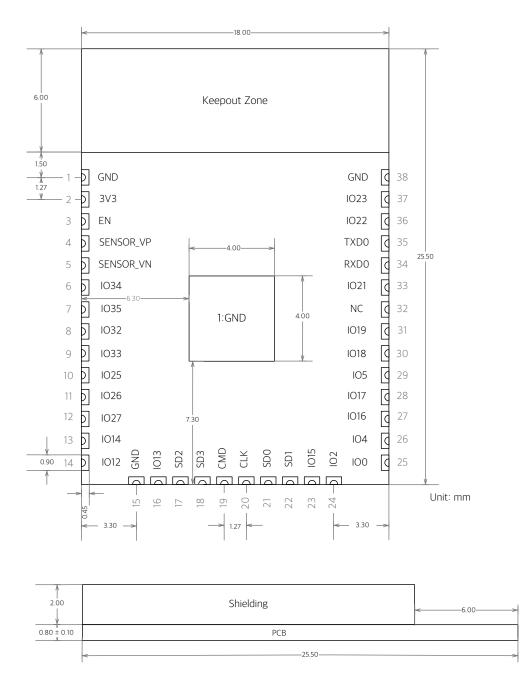


Figure 1: Top and Side View of ESP-WROOM-32

Table 2:	ESP-WROOM-32 Dimensions
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Length	Width	Height	PAD size (bottom)	Pin pitch	Shielding can height	PCB thickness
18 mm	25.5 mm	2.8 ± 0.1 mm	0.45 mm x 0.9 mm	1.27 mm	2 mm	0.8 ± 0.1 mm

2.2 Pin Description

ESP-WROOM-32 has 38 pins. See pin definitions in Table 3.

Table 3: E	SP-WROOM	-32 Pin De	finitions
------------	----------	------------	-----------

Name	No.	Function	
GND	1	Ground	
3V3	2	Power supply.	
EN	3	Chip-enable signal. Active high.	
SENSOR_VP	4	GPI36, SENSOR_VP, ADC_H, ADC1_CH0, RTC_GPI00	
SENSOR_VN	5	GPI39, SENSOR_VN, ADC1_CH3, ADC_H, RTC_GPIO3	
IO34	6	GPI34, ADC1_CH6, RTC_GPIO4	
IO35	7	GPI35, ADC1_CH7, RTC_GPIO5	
1032	8	GPIO32, XTAL_32K_P (32.768 kHz crystal oscillator input), ADC1_CH4,	
1032	0	TOUCH9, RTC_GPIO9	
IO33	9	GPIO33, XTAL_32K_N (32.768 kHz crystal oscillator output), ADC1_CH5,	
1000	9	TOUCH8, RTC_GPIO8	
IO25	10	GPIO25, DAC_1, ADC2_CH8, RTC_GPIO6, EMAC_RXD0	
IO26	11	GPIO26, DAC_2, ADC2_CH9, RTC_GPIO7, EMAC_RXD1	
IO27	12	GPIO27, ADC2_CH7, TOUCH7, RTC_GPIO17, EMAC_RX_DV	
IO14	13	GPIO14, ADC2_CH6, TOUCH6, RTC_GPIO16, MTMS, HSPICLK, HS2_CLK,	
1014	10	SD_CLK, EMAC_TXD2	
IO12	14	GPIO12, ADC2_CH5, TOUCH5, RTC_GPIO15, MTDI, HSPIQ, HS2_DATA2,	
	14	SD_DATA2, EMAC_TXD3	
GND	15	Ground	
IO13 16		GPIO13, ADC2_CH4, TOUCH4, RTC_GPIO14, MTCK, HSPID, HS2_DATA3,	
		SD_DATA3, EMAC_RX_ER	
SHD/SD2	17	GPIO9, SD_DATA2, SPIHD, HS1_DATA2, U1RXD	
SWP/SD3	18	GPIO10, SD_DATA3, SPIWP, HS1_DATA3, U1TXD	
SCS/CMD	19	GPIO11, SD_CMD, SPICSO, HS1_CMD, U1RTS	
SCK/CLK	20	GPIO6, SD_CLK, SPICLK, HS1_CLK, U1CTS	
SDO/SD0	21	GPIO7, SD_DATA0, SPIQ, HS1_DATA0, U2RTS	
SDI/SD1	22	GPIO8, SD_DATA1, SPID, HS1_DATA1, U2CTS	
IO15	23	GPIO15, ADC2_CH3, TOUCH3, MTDO, HSPICS0, RTC_GPIO13, HS2_CMD,	
	20	SD_CMD, EMAC_RXD3	
102	24	GPIO2, ADC2_CH2, TOUCH2, RTC_GPIO12, HSPIWP, HS2_DATA0,	
		SD_DATA0	
100	25	GPIO0, ADC2_CH1, TOUCH1, RTC_GPIO11, CLK_OUT1, EMAC_TX_CLK	
104	26	GPIO4, ADC2_CH0, TOUCH0, RTC_GPIO10, HSPIHD, HS2_DATA1,	
		SD_DATA1, EMAC_TX_ER	
IO16	27	GPIO16, HS1_DATA4, U2RXD, EMAC_CLK_OUT	
IO17	28	GPIO17, HS1_DATA5, U2TXD, EMAC_CLK_OUT_180	
105	29	GPIO5, VSPICS0, HS1_DATA6, EMAC_RX_CLK	
IO18	30	GPIO18, VSPICLK, HS1_DATA7	
IO19	31	GPIO19, VSPIQ, UOCTS, EMAC_TXD0	
NC	32	-	

Name	No.	Function
IO21	33	GPIO21, VSPIHD, EMAC_TX_EN
RXD0	34	GPIO3, U0RXD, CLK_OUT2
TXD0	35	GPIO1, U0TXD, CLK_OUT3, EMAC_RXD2
IO22	36	GPIO22, VSPIWP, UORTS, EMAC_TXD1
IO23	37	GPIO23, VSPID, HS1_STROBE
GND	38	Ground

2.3 Strapping Pins

ESP32 has five strapping pins. Software can read the value of these five bits from the register "GPIO_STRAPPING". During the chip power-on reset, the latches of the strapping pins sample the voltage level as strapping bits of "0" or "1", and hold these bits until the chip is powered down or shut down.

Each strapping pin is connected with its internal pull-up/pull-down during the chip reset. Consequently, if a strapping pin is unconnected or the connected external circuit is high-impendence, the internal weak pull-up/pull-down will determine the default input level of the strapping pins.

To change the strapping bit values, users can apply the external pull-down/pull-up resistances, or apply the host MCU's GPIOs to control the voltage level of these pins when powering ESP32 on.

After reset, the strapping pins work as the normal functions pins.

Refer to Table 4 for detailed boot modes of configuration by strapping pins.

	Voltage of Internal LDO (VDD_SDIO)					
Pin	Default	3.5	3V	1.8V		
MTDI	Pull-down	()	-	1	
			Booting Mode			
Pin	Default	SPI Flas	sh Boot	Downlo	ad Boot	
GPIO0	Pull-up	-	1	()	
GPIO2	Pull-down	Don't	-care	0		
		Debugging	g Log on U0TXD During	g Booting		
Pin	Default	U0TXD ⁻	Toggling	U0TXD Silent		
MTDO	Pull-up	-	1	0		
			Timing of SDIO Slave			
Pin	Default	Falling-edge Input Falling-edge Input		Rising-edge Input	Rising-edge Input	
ГШ	Delault	Falling-edge Output Rising-edge Output		Falling-edge Output	Rising-edge Output	
MTDO	Pull-up	0 0		1	1	
GPIO5	Pull-up	0	1	0	1	

Note:

Firmware can configure register bits to change the settings of "Voltage of Internal LDO (VDD_SDIO)" and "Timing of SDIO Slave" after booting.

3. Functional Description

This chapter describes the modules and functions integrated in ESP-WROOM-32.

3.1 CPU and Internal Memory

ESP32 contains two low-power Xtensa® 32-bit LX6 microprocessors. The internal memory includes:

- 448 KBytes ROM for booting and core functions.
- 520 KBytes on-chip SRAM for data and instruction.
- 8 KBytes SRAM in RTC, which is called RTC SLOW Memory and can be accessed by the co-processor during the Deep-sleep mode.
- 8 KBytes SRAM in RTC, which is called RTC FAST Memory and can be used for data storage; it is accessed by the main CPU during RTC Boot from the Deep-sleep mode.
- 1 Kbit of EFUSE, of which 256 bits are used for the system (MAC address and chip configuration) and the remaining 768 bits are reserved for customer applications, including Flash-Encryption and Chip-ID.

3.2 External Flash and SRAM

ESP32 supports 4 x 16 MBytes of external QSPI flash and SRAM with hardware encryption based on AES to protect developer's programs and data.

ESP32 accesses the external QSPI flash and SRAM through high-speed caches.

- Up to 16 MBytes of external flash are memory-mapped onto the CPU code space, supporting 8, 16 and 32-bit access. Code execution is supported.
- Up to 8 MBytes of external SRAM are memory-mapped onto the CPU data space, supporting 8, 16 and 32-bit access. Data-read is supported on the flash and SRAM. Data-write is supported on the SRAM.

3.3 Crystal Oscillators

The frequencies of the main crystal oscillator supported include 40 MHz, 26 MHz and 24 MHz. The accuracy of crystal oscillators applied should be ± 10 PPM, and the operating temperature ranges from -40°C to 85°C.

When using the downloading tools, remember to select the right crystal oscillator type. In circuit design, capacitors C1 and C2 that connect to the earth are added to the input and output terminals of the crystal oscillator, respectively. The values of the two capacitors can be flexible, ranging from 6 pF to 22 pF. However, the specific capacitive values of C1 and C2 depend on further tests and adjustments of the overall performance of the whole circuit. Normally, the capacitive values of C1 and C2 are within 10 pF when the crystal oscillator frequency is 26 MHz, or 10 pF<C1 and C2<22 pF when the crystal oscillator frequency is 40 MHz.

The frequency of the RTC crystal oscillator is typically 32 kHz or 32.768 kHz. The accuracy can be out of the range of \pm 20 PPM, when the internal calibration is applied to correct the frequency offset. When the chip operates in low-power modes, the application chooses the external low-speed (32 kHz) crystal clock, rather than the internal RC oscillators, to achieve the accurate wakeup time.

3.4 Power Consumption

With the advanced power management technology, ESP32 can switch between different power modes as follows:

- Power mode
 - Active mode: chip radio is powered on. The chip can receive, transmit, or listen.
 - Modem-sleep mode: the CPU is operational and the clock is configurable. Wi-Fi / Bluetooth baseband and radio are disabled.
 - Light-sleep mode: the CPU is paused. The RTC and ULP-coprocessor are running. Any wake-up events (MAC, host, RTC timer, or external interrupts) will wake up the chip.
 - Deep-sleep mode: Only RTC is powered on. Wi-Fi and Bluetooth connection data are stored in RTC memory. The ULP-coprocessor can work.
 - Hibernation mode: The internal 8MHz oscillator and ULP-coprocessor are disabled. The RTC recovery
 memory is powered down. Only one RTC timer on the slow clock and some RTC GPIOs are active.
 The RTC timer or the RTC GPIOs can wake up the chip from the Hibernation mode.
- Sleep Pattern
 - Association sleep pattern: The power mode switches between the active mode and Modem-sleep/Lightsleep mode during this sleep pattern. The CPU, Wi-Fi, Bluetooth, and radio wake up at pre-determined intervals to keep Wi-Fi / BT connections on.
 - ULP sensor-monitored pattern: The main CPU is in the Deep-sleep mode. The ULP co-processor does sensor measurements and wakes up the main system, based on the measured data from sensors.

The power consumption varies with different power modes/sleep patterns, and work status, of functional modules (see Table 5).

Power mode	Comment	Power consumption
	Wi-Fi Tx packet 13 dBm ~ 21 dBm	160 ~ 260 mA
Active mode (RF working)	Wi-Fi / BT Tx packet 0 dBm	120 mA
Active mode (ni working)	Wi-Fi / BT Rx and listening	80 ~ 90 mA
	Association sleep pattern (by Light-	0.9 mA@DTIM3, 1.2 mA@DTIM1
	sleep)	
		Max speed: 20 mA
Modem-sleep mode	The CPU is powered on.	Normal: 5 ~ 10 mA
		Slow speed: 3 mA
Light-sleep mode	-	0.8 mA
	The ULP-coprocessor is powered on.	0.15 mA
Deep-sleep mode	ULP sensor-monitored pattern	25 μA @1% duty
	RTC timer + RTC memories	20 µA
Hibernation mode	RTC timer only	5 μΑ

Table 5: Pow	ver Consumption	by Power Modes
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3.5 Peripherals and Sensors

3.5.1 Peripherals and Sensors Description

Table 6: Peripherals and Sensors Description

Interface	Signal	Pin	Function
	ADC1_CH0	SENSOR_VP	
	ADC1_CH3	SENSOR_VN	
	ADC1_CH4	IO32	
	ADC1_CH5	IO33	
	ADC1_CH6	IO34	
	ADC1_CH7	IO35	
	ADC2_CH0	IO4	
ADC	ADC2_CH1	I1IO0Two 12-bit SAR ADCsI2IO2	
	ADC2_CH2	IO2	
	ADC2_CH3	IO15	
	ADC2_CH4	IO13	
	ADC2_CH5	IO12	
	ADC2_CH6	IO14	
	ADC2_CH7	IO27	
	ADC2_CH8	IO25	
	ADC2_CH9	IO26	
Ultra Low Noise	SENSOR_VP	IO36	Provides about 60dB gain by using larger
Analog Pre-Amplifier	SENSOR_VN	IO39	capacitors on PCB
DAC	DAC_1	IO25	- Two 8-bit DACs
DAG	DAC_2	IO26	- TWO 8-DIL DACS
	TOUCHO	IO4	
	TOUCH1	IOO	
	TOUCH2	IO2	
	ТОИСНЗ	IO15	
Touch Sensor	TOUCH4	IO13	Capacitive touch sensors
	TOUCH5	IO12	
	TOUCH6	IO14	
	TOUCH7	IO27	
	TOUCH8	IO33	
	TOUCH9	IO32	
	HS2_CLK	MTMS	
	HS2_CMD	MTDO	
SD / SDIO / MMC	HS2_DATA0	102	Supports SD memory card V3.01 standard
Host Controller	HS2_DATA1	IO4	
	HS2_DATA2	MTDI	
	HS2_DATA3	MTCK	

Interface	Signal	Pin	Function	
	PWM0_OUT0~2			
	PWM1_OUT_IN0~2		Three channels of 16-bit timers generate	
	PWM0_FLT_IN0~2		PWM waveforms; each has a pair of	
Motor PWM	PWM1_FLT_IN0~2	Any GPIO	output signals. Three fault detection	
	PWM0_CAP_IN0~2		signals. Three even capture signals. Three	
	PWM1_CAP_IN0~2		sync signals.	
	PWM0_SYNC_IN0~2			
	PWM1_SYNC_IN0~2			
LED PWM	ledc_hs_sig_out0~7		16 independent channels @80MHz	
	ledc_ls_sig_out0~7	- Any GPIO	clock/RTC CLK. Duty accuracy: 16bits.	
	U0RXD_in			
	U0CTS_in			
	U0DSR_in			
	U0TXD_out	Any GPIO		
	UORTS_out			
	U0DTR_out			
UART	U1RXD_in		Two UART devices with hardware flow-control and DMA	
	U1CTS_in			
	U1TXD_out			
	U1RTS_out			
	U2RXD_in			
	U2CTS_in			
	U2TXD_out			
	U2RTS_out			
	I2CEXT0_SCL_in			
	I2CEXT0_SDA_in			
	I2CEXT1_SCL_in			
12C	I2CEXT1_SDA_in	Any GPIO	Two I2C devices in slave or master modes	
	I2CEXT0_SCL_out			
	I2CEXT0_SDA_out			
	I2CEXT1_SCL_out			
	I2CEXT1_SDA_out			

Interface	Signal	Pin	Function		
	I2S0I_DATA_in0~15				
	I2S00_BCK_in				
	I2S0O_WS_in	-			
	I2S0I_BCK_in				
	I2S0I_WS_in				
	I2S0I_H_SYNC				
	I2S0I_V_SYNC				
	I2S0I_H_ENABLE				
	I2S0O_BCK_out				
	I2S0O_WS_out				
	I2S0I_BCK_out				
	I2S0I_WS_out	Any GPIO			
12S	I2SOO_DATA_out0~23		Stereo input and output from/to the audio codec, and parallel LCD data output		
	I2S1I_DATA_in0~15				
	I2S10_BCK_in				
	I2S10_WS_in				
	I2S1I_BCK_in				
	I2S1I_WS_in				
	I2S1I_H_SYNC				
	I2S1I_V_SYNC				
	I2S1I_H_ENABLE				
	I2S1O_BCK_out				
	I2S10_WS_out				
	I2S1I_BCK_out				
	I2S1I_WS_out				
	I2S1O_DATA_out0~23				
Remote Controller	RMT_SIG_IN0~7		Eight channels of IR transmitter and		
	RMT_SIG_OUT0~7	Any GPIO	receiver for various waveforms		

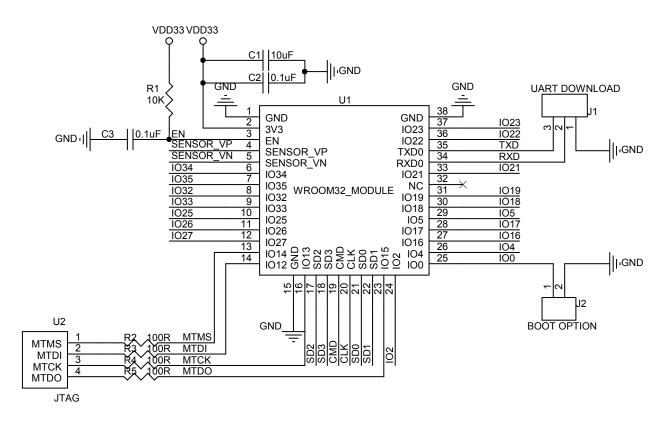
Interface	Signal	Pin	Function
	SPIHD	SHD/SD2	
	SPIWP	SWP/SD3	
	SPICS0	SCS/CMD	
	SPICLK	SCK/CLK	
	SPIQ	SDO/SD0	
	SPID	SDI/SD1	
	HSPICLK	IO14	
	HSPICS0	IO15	Supports Standard SPI, Dual SPI, and
Parallel QSPI	HSPIQ	IO12	Quad SPI that can be connected to the
	HSPID	IO13	external flash and SRAM
	HSPIHD	IO4	
	HSPIWP	IO2	
	VSPICLK	IO18	
	VSPICS0	IO5	
	VSPIQ	IO19	
	VSPID	IO23	
	VSPIHD	IO21	
	VSPIWP	IO22	
	HSPIQ_in/_out		Standard SPI consists of clock,
	HSPID_in/_out		chip-select, MOSI and MISO. These SPIs
	HSPICLK_in/_out		can be connected to LCD and other
	HSPI_CS0_in/_out		external devices. They support the
	HSPI_CS1_out		following features:
General Purpose	HSPI_CS2_out	Any GPIO	(a) both master and slave modes;
SPI	VSPIQ_in/_out	,	(b) 4 sub-modes of the SPI format transfer
	VSPID_in/_out		that depend on the clock phase (CPHA)
	VSPICLK_in/_out		and clock polarity (CPOL) control;
	VSPI_CS0_in/_out		(c) CLK frequencies by a divider;
	VSPI_CS1_out		(d) up to 64byte FIFO and DMA.
	VSPI_CS2_out		
	MTDI	IO12	
JTAG	MTCK	IO13	JTAG for software debugging
	MTMS	IO14	- orad for sortware debugging
	MTDO	IO15	

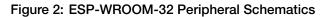
Interface	Signal	Pin	Function
	SD_CLK	IO6	
	SD_CMD	IO11	SDIO interface that conforms to the
SDIO Slave	SD_DATA0	107	industry standard SDIO 2.0 card
SDIO Slave	SD_DATA1	IO8	specification.
	SD_DATA2	109	
	SD_DATA3	IO9 . IO10 . IO0 . IO5 . IO21 . IO19 . IO22 .	
	EMAC_TX_CLK	IOO	
	EMAC_RX_CLK	IO5	
	EMAC_TX_EN	IO21	
	EMAC_TXD0	IO19	
	EMAC_TXD1	IO22	
	EMAC_TXD2	IO14	
	EMAC_TXD3	IO12	
	EMAC_RX_ER	IO13	
	EMAC_RX_DV	1027	
	EMAC_RXD0	IO25	
EMAC	EMAC_RXD0IO25EMAC_RXD1IO26	IO26	Ethernet MAC with MII/RMII interface
	EMAC_RXD2	TXD	
	EMAC_RXD3	IO15	
	EMAC_CLK_OUT	IO16	
	EMAC_CLK_OUT_180	IO17	
	EMAC_TX_ER	IO4	
	EMAC_MDC_out	Any GPIO	
	EMAC_MDI_in	Any GPIO	
	EMAC_MDO_out	Any GPIO	
	EMAC_CRS_out	Any GPIO	
	EMAC_COL_out	Any GPIO	

Note:

Functions of Motor PWM, LED PWM, UART, I2C, I2S, general purpose SPI and Remote Controller can be configured to any GPIO.

3.5.2 Peripheral Schematics





Note:

The MTDI should be kept at low electric level.

4. Electrical Characteristics

Note:

The specifications in this chapter have been tested under the following general condition: $V_{BAT} = 3.3V$, $T_A = 27^{\circ}C$, unless otherwise specified.

4.1 Absolute Maximum Ratings

Table 7: Absolute Maximum Ratings

Rating	Condition	Value	Unit
Storage temperatue	-	-40 ~ 85	°C
Maximum soldering temperature	-	260	°C
Supply voltage	IPC/JEDEC J-STD-020	+2.2 ~ +3.6	V

4.2 Recommended Operating Conditions

Table 8: Recommended Operating Conditions

Operating condition	Symbol	Min	Тур	Max	Unit
Operating temperature	-	-40	20	85	°C
Supply voltage	VDD	2.2	3.3	3.6	V

4.3 Digital Terminal Characteristics

Table 9: Digital Terminal Characteristics

Terminals	Symbol	Min	Тур	Max	Unit
Input logic level low	V _{IL}	-0.3	-	0.25VDD	V
Input logic level high	V_{IH}	0.75VDD	-	VDD+0.3	V
Output logic level low	V _{OL}	N	-	0.1VDD	V
Output logic level high	V _{OH}	0.8VDD	-	N	V

4.4 Wi-Fi Radio

Description	Min	Typical	Max	Unit			
General Characteristics							
Input frequency	2412	-	2484	MHz			
Input impedance	-	50	-	Ω			
Input reflection	-	-	-10	dB			
Output power of PA	15.5	16.5	21.5	dBm			
	Sensit	ivity	· ·				
DSSS, 1 Mbps	-	-98	-	dBm			
CCK, 11 Mbps	-	-90	-	dBm			
OFDM, 6 Mbps	-	-93	-	dBm			
OFDM, 54 Mbps	-	-75	-	dBm			
HT20, MCS0	-	-93	-	dBm			
HT20, MCS7	-	-73	-	dBm			
HT40, MCS0	-	-90	-	dBm			
HT40, MCS7	-	-70	-	dBm			
MCS32	-	-91	-	dBm			
	Adjacent Channel Rejection						
OFDM, 6 Mbps	-	37	-	dB			
OFDM, 54 Mbps	-	21	-	dB			
HT20, MCS0	-	37	-	dB			
HT20, MCS7	-	20	-	dB			

Table 10: Wi-Fi Radio Characteristics

4.5 Bluetooth LE Radio

4.5.1 Receiver

Table 11: Receiver Characteristics - BLE

Parameter	Conditions	Min	Тур	Max	Unit
Sensitivity @0.1% BER	-	-	-98	-	dBm
Maximum received signal @0.1% BER	-	0	-	-	dBm
Co-channel C/I	-	-	+10	-	dB
Adjacent channel selectivity C/I	F = F0 + 1 MHz	-	-5	-	dB
	F = F0 - 1 MHz	-	-5	-	dB
	F = F0 + 2 MHz	-	-25	-	dB
	F = F0 - 2 MHz	-	-35	-	dB
	F = F0 + 3 MHz	-	-25	-	dB
	F = F0 - 3 MHz	-	-45	-	dB
Out-of-band blocking performance	30 MHz - 2000 MHz	-10	-	-	dBm
	2000 MHz - 2400 MHz	-27	-	-	dBm
	2500 MHz - 3000 MHz	-27	-	-	dBm
	3000 MHz - 12.5 GHz	-10	-	-	dBm
Intermodulation	-	-36	-	-	dBm

4.5.2 Transmit

Parameter	Conditions	Min	Тур	Max	Unit
RF transmit power	-	-	+7.5	+10	dBm
RF power control range	-	-	25	-	dB
Adjacent channel transmit power	F = F0 + 1 MHz	-	-14.6	-	dBm
	F = F0 - 1 MHz	-	-12.7	-	dBm
	F = F0 + 2 MHz	-	-44.3	-	dBm
	F = F0 - 2 MHz	-	-38.7	-	dBm
	F = F0 + 3 MHz	-	-49.2	-	dBm
	F = F0 - 3 MHz	-	-44.7	-	dBm
	F = F0 + > 3 MHz	-	-50	-	dBm
	F = F0 - > 3 MHz	-	-50	-	dBm
$\Delta f1_{avg}$	-	-	-	265	kHz
Δ f2 _{max}	-	247	-	-	kHz
Δ f2 $_{avg}/\Delta$ f1 $_{avg}$	-	-	-0.92	-	-
ICFT	-	-	-10	-	kHz
Drift rate	-	-	0.7	-	kHz/50 μ s
Drift	-	-	2	-	kHz

Table 12: Transmit Characteristics - BLE

4.6 Reflow Profile

Table 13: Reflow Profile

Item	Value		
T _s max to TL (Ramp-up Rate)	3°C/second max		
Preheat			
Temperature Min. (T _s Min.)	150°C		
Temperature Typ. (T _s Typ.)	175°C		
Temperature Min. (T _s Max.)	200°C		
Time (T _s)	60 ~ 180 seconds		
Ramp-up rate (T_L to T_P)	3°C/second max		
Time maintained above: –Temperature (T_L) /Time (T_L)	217°C/60 ~ 150 seconds		
Peak temperature (T_P)	260°C max, for 10 seconds		
Target peak temperature (T _P Target)	260°C +0/-5°C		
Time within 5°C of actual peak (t_P)	20 ~ 40 seconds		
T_S max to T_L (Ramp-down Rate)	6°C/second max		
Tune 25°C to Peak Temperature (t)	8 minutes max		

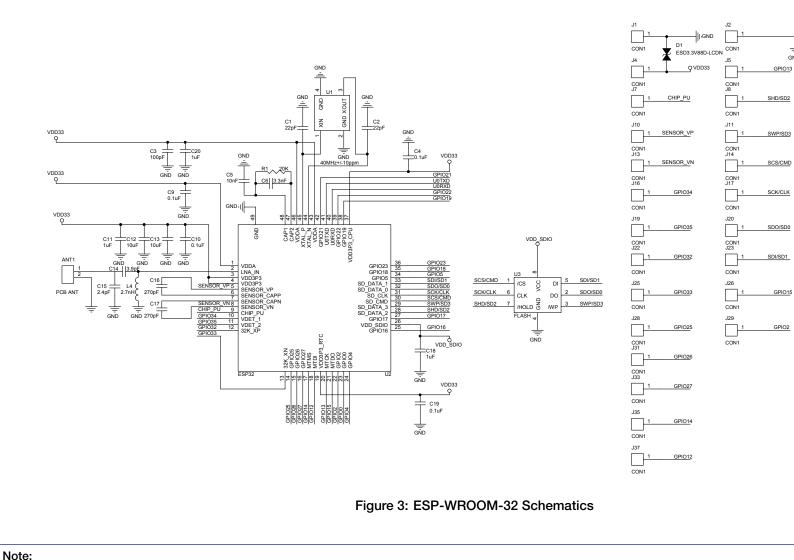
Note:

The 32 kHz crystal is internally connected to ESP32's GPIO32 and GPIO33. To use ADC, Touch or GPIO functions of IO32 and IO33, please remove the 32 kHz crystal and its capacitors — C13 and C17, and solder the 0ohm resistors — R5 and R6.

5. Schematics



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CON1

CON1 J9

CON1

J12

CON1 J15

CON1 J18

CON1

CON1 J24

CON1

J27

CON1

J30

CON1 J32

CON1 J34

CON1

CON1

CON1

J38

J36

J21

J6

GPIO23

GPI022

UOTXD

UORXD

GPIO21

GPIO19

GPIO18

GPI05

GPIO17

GPIO16

GPIO4

GPI00